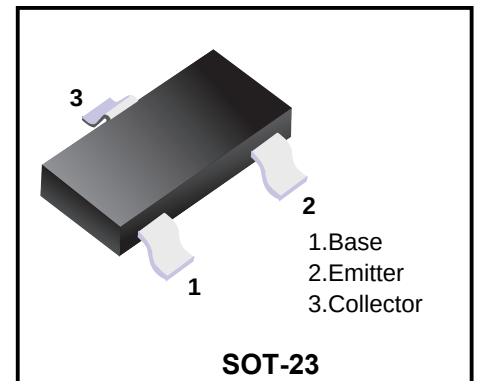


PNP Transistors

Features

- Ideal for Medium Power Amplification and Switching
- Complementary NPN Type Available (MMBT4401)

Marking Code	
MMBT4403	2T



Absolute Maximum Ratings (Ta=25°C)

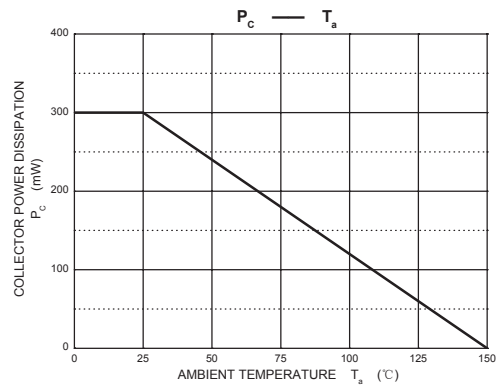
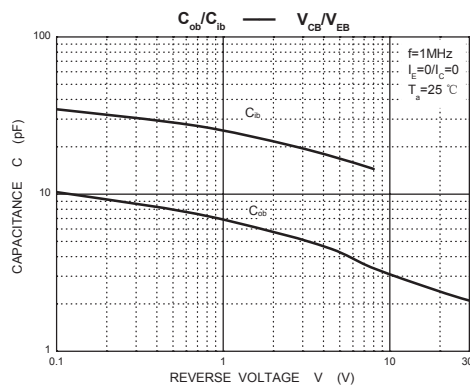
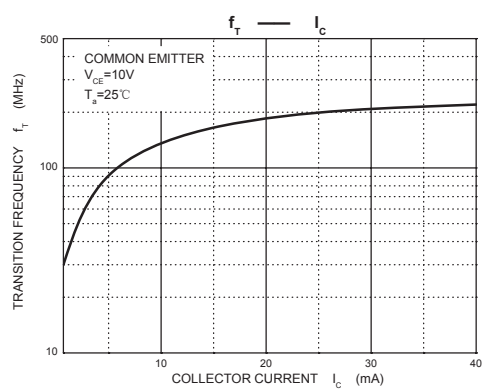
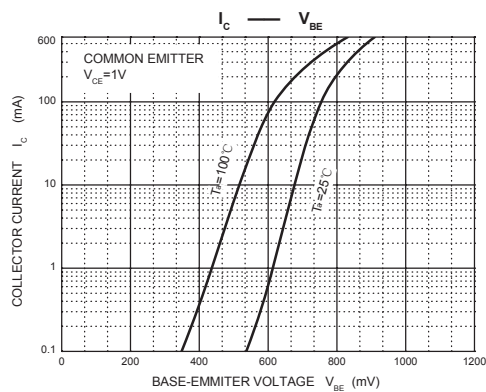
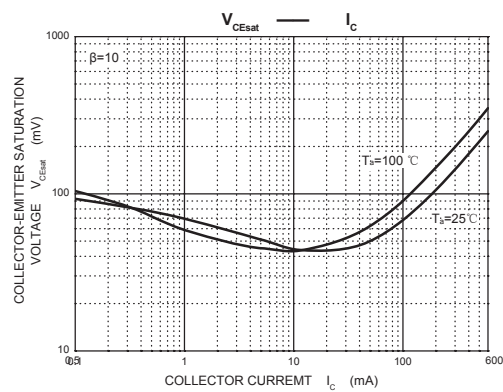
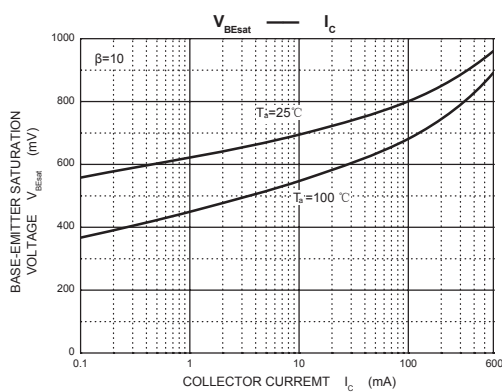
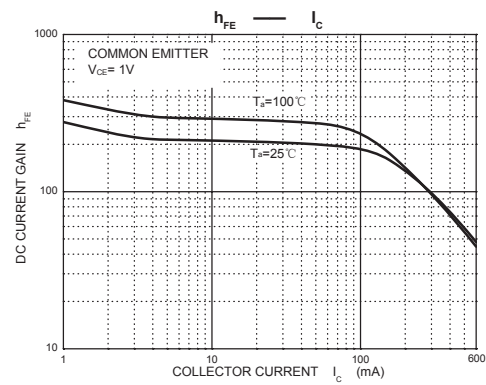
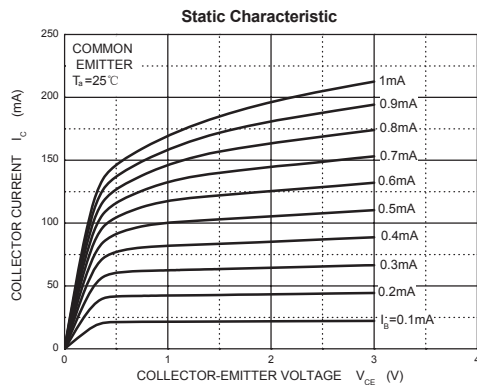
Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-40	V
Collector-emitter voltage	V _{CEO}	-40	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	I _C	-600	mA
Total Device Dissipation Alumina Substrate	P _D	300	mW
Thermal Resistance, Junction to Ambient	R _{θJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to 150	°C

Electrical Characteristics (Ta=25°C unless otherwise specified.)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 100μA, I _E = 0	-40			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = 1.0 mA, I _B = 0	-40			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = 100μA, I _C = 0	-5			V
Collector cut-off current	I _{CBO}	V _{CB} = -35 V, I _E = 0			-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -4 V, I _C = 0			-0.1	μA
DC current gain *	h _{FE}	I _C = -0.1 mA, V _{CE} = -1.0 V I _C = -1.0 mA, V _{CE} = -1.0 V I _C = -10 mA, V _{CE} = -1.0 V I _C = -150 mA, V _{CE} = -2.0 V I _C = -500 mA, V _{CE} = -2.0 V	30 60 100 100 20		300	
Collector-emitter saturation voltage *	V _{CE(sat)}	I _C = -150 mA, I _B = -15 mA			-0.4	V
		I _C = -500 mA, I _B = -50 mA			-0.75	
Base-emitter saturation voltage *	V _{BE(sat)}	I _C = 150 mA, I _B = 15 mA	-0.75		-0.95	V
		I _C = 500 mA, I _B = 50 mA			-1.3	
Transition frequency	f _T	I _C = 20 mA, V _{CE} = 10 V, f = 100 MHz	200			MHz
Delay time	t _d	V _{CC} = 30 V, V _{EB} = 2.0 V,			15	ns
Rise time	t _r	I _C = 150 mA, I _{B1} = 15 mA			20	ns
Storage time	t _s	V _{CC} = 30 V, I _C = 150 mA,			225	ns
Fall time	t _f	I _{B1} = I _{B2} = 15 mA			30	ns

* Pulse test: pulse width ≤ 300 μs, duty cycle ≤ 2.0%.

Typical Characteristics



Ordering information

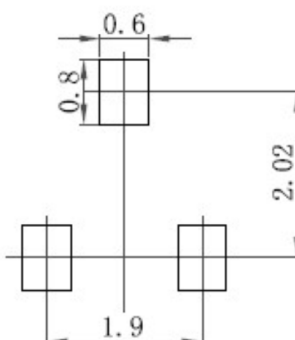
Package	Packing Description	Base Quantity	Packing Quantity
SOT-23	Tape/Reel, 7" reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

Package Dimensions

SOT-23

Dim.	Millimeter (mm)		mil	
	Min.	Max.	Min.	Max.
A	0.9	1.15	35	45
A1	0.1		3.9	
bp	0.38	0.48	15	19
C	0.09	0.15	3.54	5.9
D	2.8	3.0	110	118
E	1.2	1.4	47	55
E	1.9		75	
E1	0.95		37	
HE	2.1	2.55	83	100
Lp	0.15	0.45	5.9	18
Q	0.45	0.55	18	22
v	0.2		7.9	
W	0.1		4	

The recommended mounting pad size



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